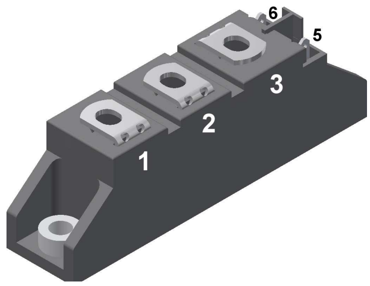
Thyristor Module

V_{RRM} = 2x 1400 V
I_{TAV} = 18 A
V_T = 1.57 V

Phase leg

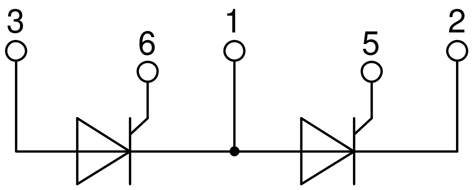
Part number

MCC19-14io8B



Backside: isolated

E72873



Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al2O3-ceramic

Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

Package: TO-240AA

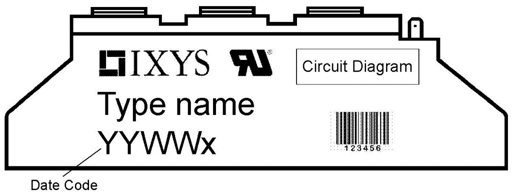
- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Thyristor

Symbol	Definition	Conditions		Ratings min.	typ.	max.	Unit
$V_{RSM/DSM}$	*max. non-repetitive reverse/forward blocking voltage*		T_{VJ} = 25°C			1500	V
$V_{RRM/DRM}$	*max. repetitive reverse/forward blocking voltage*		T_{VJ} = 25°C			1400	V
$I_{R/D}$	*reverse current, drain current*	$V_{R/D}$ = 1400 V	T_{VJ} = 25°C			100	µA
		$V_{R/D}$ = 1400 V	T_{VJ} = 125°C			3	mA
V_T	*forward voltage drop*	I_T = 40 A	T_{VJ} = 25°C			1.56	V
		I_T = 80 A				2.05	V
		I_T = 40 A	T_{VJ} = 125°C			1.57	V
		I_T = 80 A				2.29	V
I_{TAV}	*average forward current*	T_C = 85°C	T_{VJ} = 125°C			18	A
$I_{T(RMS)}$	*RMS forward current*	180° sine				28	A
V_{T0}	*threshold voltage*	*for power loss calculation only*	T_{VJ} = 125°C			0.85	V
r_T	*slope resistance*					18	mΩ
R_{thJC}	*thermal resistance junction to case*					1.3	K/W
R_{thCH}	*thermal resistance case to heatsink*				0.2		K/W
P_{tot}	*total power dissipation*		T_C = 25°C			77	W
I_{TSM}	*max. forward surge current*	t = 10 ms; (50 Hz), sine	T_{VJ} = 45°C			400	A
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			430	A
		t = 10 ms; (50 Hz), sine	T_{VJ} = 125°C			340	A
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			365	A
I^2t	*value for fusing*	t = 10 ms; (50 Hz), sine	T_{VJ} = 45°C			800	A²s
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			770	A²s
		t = 10 ms; (50 Hz), sine	T_{VJ} = 125°C			580	A²s
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			555	A²s
C_J	*junction capacitance*	V_R = 400 V f = 1 MHz	T_{VJ} = 25°C		22		pF
P_{GM}	*max. gate power dissipation*	t_P = 30 µs	T_C = 125°C			10	W
		t_P = 300 µs				5	W
P_{GAV}	*average gate power dissipation*					0.5	W
$(di/dt)_{cr}$	*critical rate of rise of current*	T_{VJ} = 125 °C; f = 50 Hz	repetitive, I_T = 75 A			150	A/µs
		t_P = 200 µs; di_G/dt = 0.45 A/µs;					
		I_G = 0.45 A; V = ⅔ V_{DRM}	non-repet., I_T = 18 A			500	A/µs
$(dv/dt)_{cr}$	*critical rate of rise of voltage*	V = ⅔ V_{DRM}	T_{VJ} = 125°C			1000	V/µs
		R_{GK} = ∞; method 1 (linear voltage rise)					
V_{GT}	*gate trigger voltage*	V_D = 6 V	T_{VJ} = 25°C			1.5	V
			T_{VJ} = -40°C			1.6	V
I_{GT}	*gate trigger current*	V_D = 6 V	T_{VJ} = 25°C			100	mA
			T_{VJ} = -40°C			200	mA
V_{GD}	*gate non-trigger voltage*	V_D = ⅔ V_{DRM}	T_{VJ} = 125°C			0.2	V
I_{GD}	*gate non-trigger current*					5	mA
I_L	*latching current*	t_p = 10 µs	T_{VJ} = 25°C			450	mA
		I_G = 0.45 A; di_G/dt = 0.45 A/µs					
I_H	*holding current*	V_D = 6 V R_{GK} = ∞	T_{VJ} = 25°C			200	mA
t_{gd}	*gate controlled delay time*	V_D = ½ V_{DRM}	T_{VJ} = 25°C			2	µs
		I_G = 0.45 A; di_G/dt = 0.45 A/µs					
t_q	*turn-off time*	V_R = 100 V; I_T = 20A; V = ⅔ V_{DRM}	T_{VJ} = 100 °C		150		µs
		di/dt = 10 A/µs dv/dt = 20 V/µs	t_p = 200 µs				

Package TO-240AA

Symbol	Definition	Conditions			Ratings min.	typ.	max.	Unit
I_{RMS}	*RMS current*	per terminal					200	A
T_{VJ}	*virtual junction temperature*				-40		125	°C
T_{op}	*operation temperature*				-40		100	°C
T_{stg}	*storage temperature*				-40		125	°C
Weight						81		g
M_D	*mounting torque*				2.5		4	Nm
M_T	*terminal torque*				2.5		4	Nm
$d_{Spp/App}$	*creepage distance on surface | striking distance through air*		*terminal to terminal*	13.0	9.7			mm
$d_{Spb/Apb}$			*terminal to backside*	16.0	16.0			mm
V_{ISOL}	*isolation voltage*	t = 1 second	50/60 Hz, RMS; I_{ISOL} ≤ 1 mA		4800			V
		t = 1 minute			4000			V

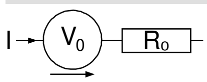


Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCC19-14io8B	MCC19-14io8B	Box	36	457817

Similar Part	Package	Voltage class
MCMA25P1600TA	TO-240AA-1B	1600
MCMA35P1600TA	TO-240AA-1B	1600

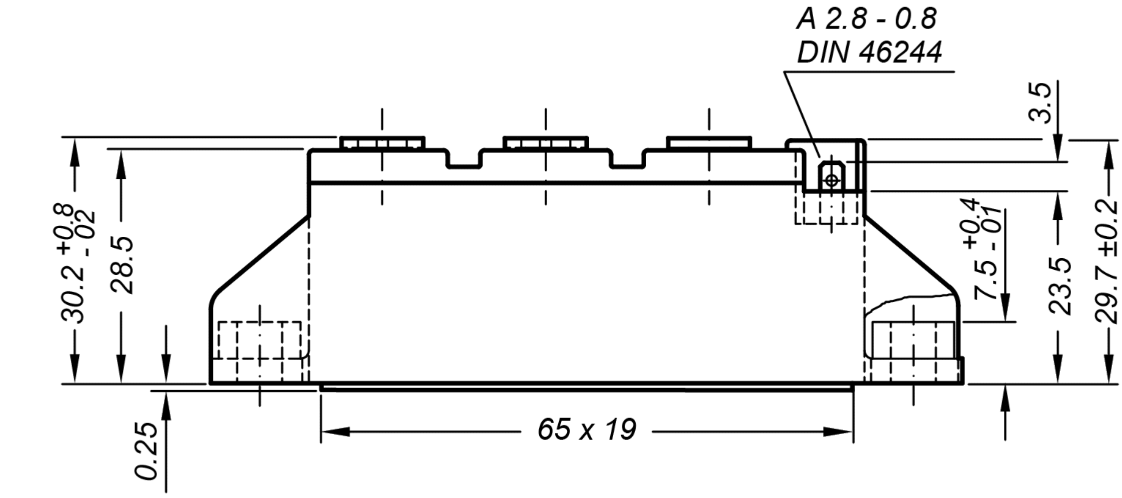
Equivalent Circuits for Simulation

* on die level $T_{VJ} = 125°C$

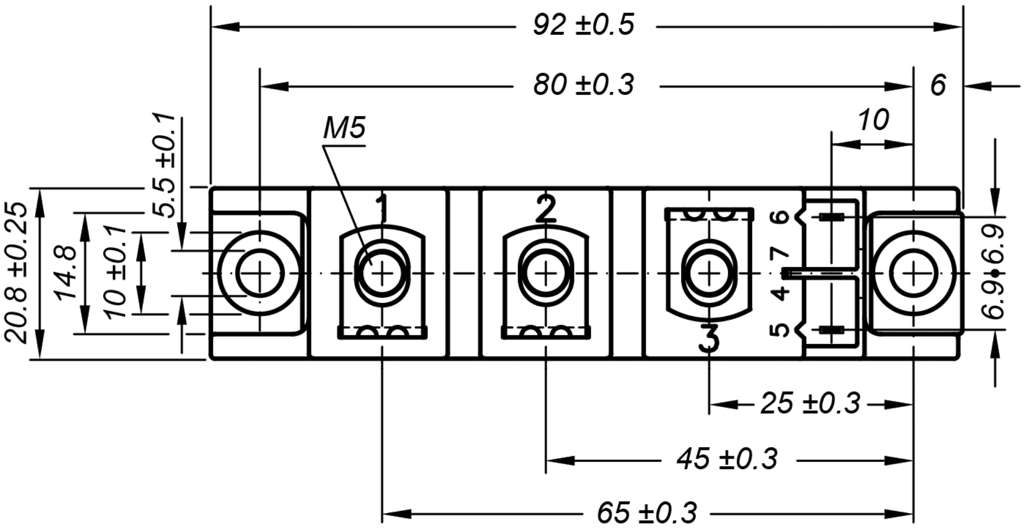


		Thyristor	
$V_{0\ max}$	*threshold voltage*	0.85	V
$R_{0\ max}$	*slope resistance **	16.8	mΩ

Outlines TO-240AA



General tolerance: DIN ISO 2768 class „c“

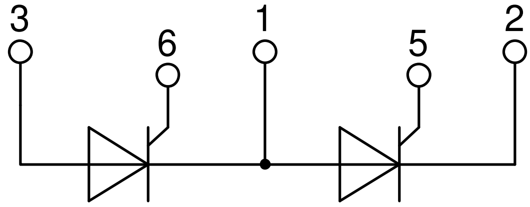


Optional accessories for modules

Keyed gate/cathode twin plugs with wire length = 350 mm, gate = white, cathode = red

Type ZY 200L (L = Left for pin pair 4/5) } UL 758, style 3751

Type ZY 200R (R = Right for pin pair 6/7) }



Thyristor

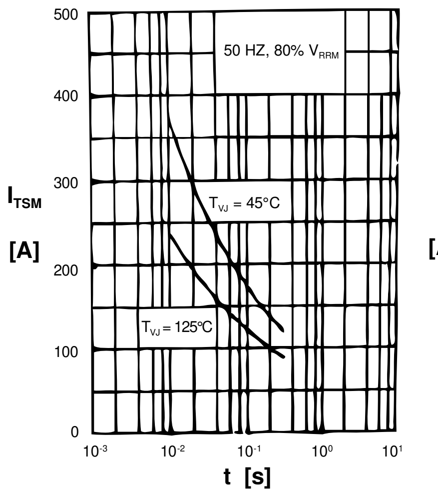


Fig. 1 Surge overload current
I_{TSM}: Crest value, t: duration

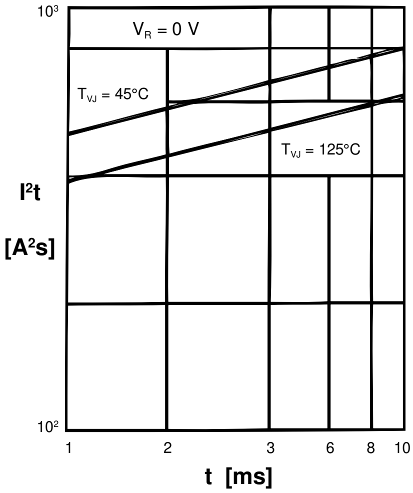


Fig. 2 I²t versus time (1-10 ms)

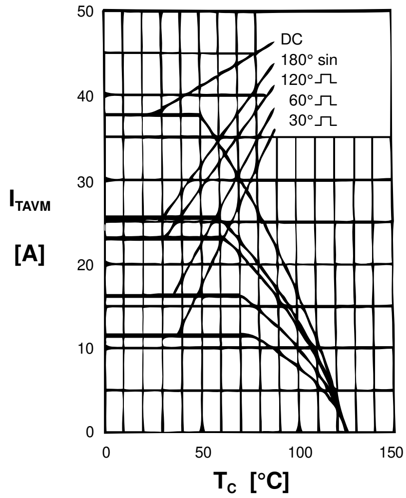


Fig. 3 Max. forward current
at case temperature

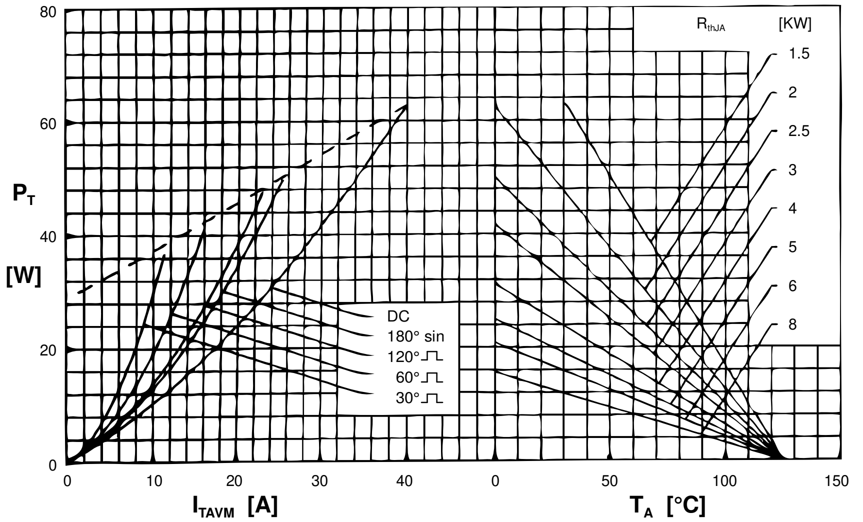


Fig. 4 Power dissipation versus onstate current & ambient temp. (per thyristor)

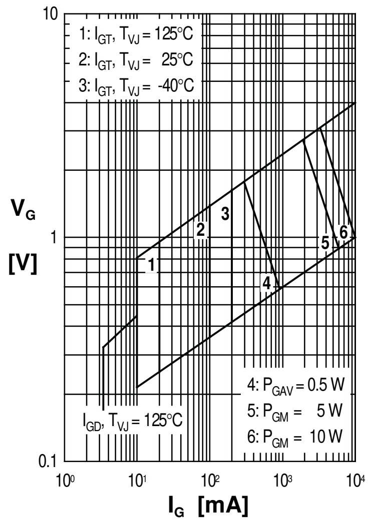


Fig. 5 Gate trigger charact.

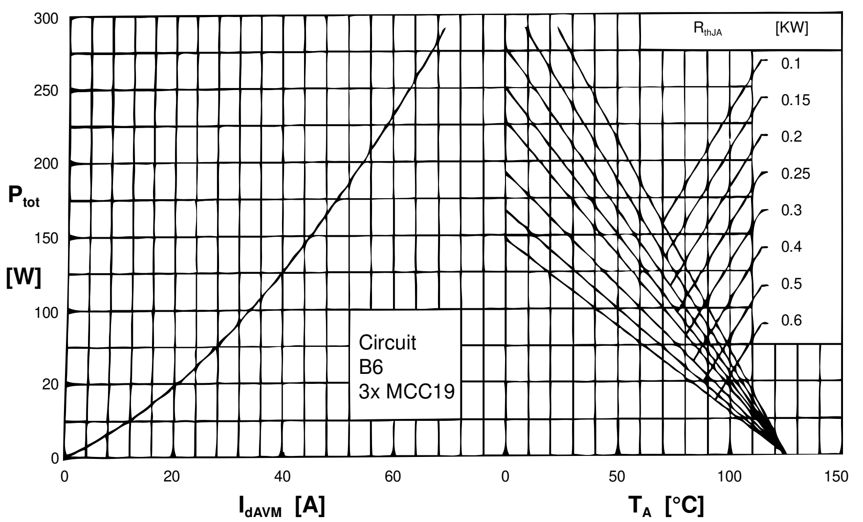


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct
output current and ambient temperature

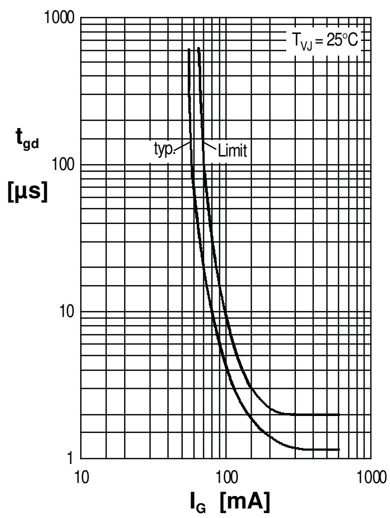


Fig. 7 Gate trigger delay time

Thyristor

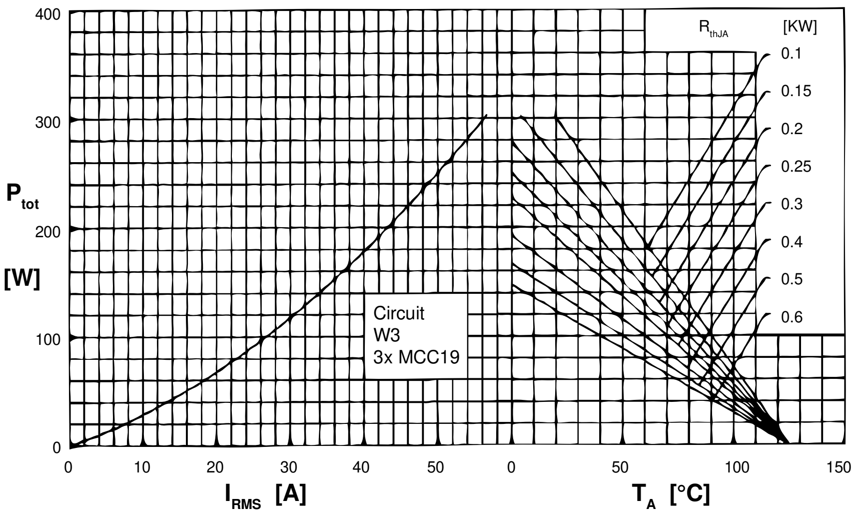


Fig. 8 Three phase AC-controller: Power dissipation vs. RMS output current and ambient temperature

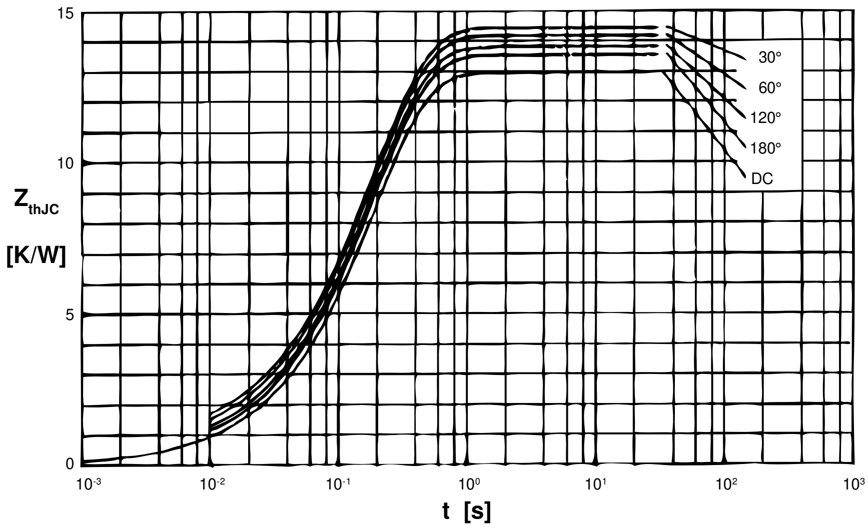


Fig. 9 Transient thermal impedance junction to case (per thyristor)

R_{thJC} for various conduction angles d:

d	R_{thJC} [K/W]
DC	1.30
180°	1.35
120°	1.39
60°	1.42
30°	1.45

Constants for Z_{thJC} calculation:

i	R_{thi} [K/W]	t_i [s]
1	0.018	0.0033
2	0.041	0.0216
3	1.241	0.1910

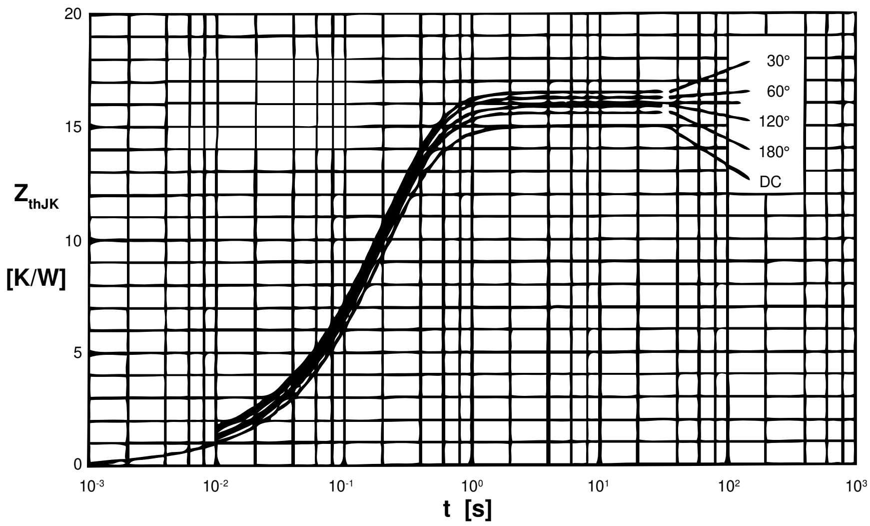


Fig. 10 Transient thermal impedance junction to heatsink (per thyristor)

R_{thJK} for various conduction angles d:

d	R_{thJK} [K/W]
DC	1.50
180°	1.55
120°	1.59
60°	1.62
30°	1.65

Constants for Z_{thJK} calculation:

i	R_{thi} [K/W]	t_i [s]
1	0.018	0.0033
2	0.041	0.0216
3	1.241	0.1910
4	0.200	0.4600